

➤ 产品外观 / Appearance

Preliminary



$V_{CES} = 1200V$

$I_{C\text{nom}} = 75A / I_{CRM} = 150A$

➤ 特性 / Features

- A. 低饱和压降
- B. 低开关损耗
- C. 低电感模块结构

- A. Low V_{CEsat}
- B. Low Switching Losses
- C. Low Inductance Module Structure

➤ 用途 / Applications

- A. 电机传动
- B. 不间断电源应用
- C. 高频开关应用

- A. Motor Drives
- B. UPS Systems
- C. High Frequency Switching Application

➤ 相关信息 / Related Information

条形码 / Barcode Code



二维码 / DMX – Code



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CHA75ZL120S1P

IGBT, 制动-斩波器 / IGBT, Brake-Chopper



最大额定值 / Maximum Rated Values

集电极-发射极电压 Collector-emitter voltage	$T_j = 25^\circ\text{C}$	V_{CES}	1200	V
连续集电极直流电流 Continuous DC collector current	$T_C = 80^\circ\text{C}, T_{j\max} = 150^\circ\text{C}$	$I_{C\text{nom}}$	75	A
集电极重复峰值电流 Repetitive peak collector current	$t_p = 1\text{ ms}$	I_{CRM}	150	A
栅极-发射极峰值电压 Gate-emitter peak voltage		V_{GES}	+/-20	V

特征值 / Characteristic Values

			Min.	Typ.	Max.	
集电极-发射极饱和电压 Collector-emitter saturation voltage	$I_C = 75\text{ A}, V_{GE} = 15\text{ V}$	$T_j = 25^\circ\text{C}$ $T_j = 125^\circ\text{C}$	$V_{CE\text{sat}}$	1.95 2.15	2.25	V
栅极阈值电压 Gate threshold voltage	$I_C = 3\text{ mA}, V_{CE} = V_{GE}, T_j = 25^\circ\text{C}$		$V_{G\text{eth}}$	5.0	5.8	6.5
内部栅极电阻 Internal gate resistor	$T_j = 25^\circ\text{C}$		$R_{G\text{int}}$	2.5		Ω
输入电容/Input capacitance	$f = 1\text{ MHz}, T_j = 25^\circ\text{C}, V_{CE} = 25\text{ V}, V_{GE} = 0\text{ V}$		C_{ies}	4.2		nF
反向传输电容 Reverse transfer capacitance			C_{res}	0.32		nF
集电极-发射极截止电流 Collector-emitter cut-off current	$V_{CE} = 1200\text{ V}, V_{GE} = 0\text{ V}, T_j = 25^\circ\text{C}$		I_{CES}		1.0	mA
栅极-发射极漏电流 Gate-emitter leakage current	$V_{CE} = 0\text{ V}, V_{GE} = 20\text{ V}, T_j = 25^\circ\text{C}$		I_{GES}		100	nA
开通延迟时间 Turn-on delay time	$I_C = 75\text{ A}, V_{CE} = 600\text{ V}$ $V_{GE} = \pm 15\text{ V}$ $R_G = 5.1\ \Omega$ Inductive Load	$T_j = 25^\circ\text{C}$ $T_j = 125^\circ\text{C}$	$t_{d\text{on}}$	80 90		ns
上升时间/Rise time		$T_j = 25^\circ\text{C}$ $T_j = 125^\circ\text{C}$	t_r	85 90		ns
关断延迟时间 Turn-off delay time		$T_j = 25^\circ\text{C}$ $T_j = 125^\circ\text{C}$	$t_{d\text{off}}$	455 520		ns
下降时间/Fall time		$T_j = 25^\circ\text{C}$ $T_j = 125^\circ\text{C}$	t_f	36 40		ns
开通损耗能量 Turn-on energy loss		$T_j = 25^\circ\text{C}$ $T_j = 125^\circ\text{C}$	E_{on}	7.1 10.4		mJ
关断损耗能量 Turn-off energy loss		$T_j = 25^\circ\text{C}$ $T_j = 125^\circ\text{C}$	E_{off}	5.7 8.0		mJ
短路数据/SC data	$V_{GE} \leq 15\text{ V}, V_{CC} = 600\text{ V}$ $t_p \leq 10\ \mu\text{s}, T_j = 125^\circ\text{C}$		I_{SC}	370		A
结 - 外壳热阻 Thermal resistance, junction to case	每个 IGBT / per IGBT		R_{thJC}		0.28	K/W
在开关状态下温度 Temperature under switching			$T_{j\text{op}}$	-40	125	$^\circ\text{C}$

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二极管, 斩波器 / Diode, Chopper



最大额定值 / Maximum Rated Values

反向重复峰值电压 Repetitive peak reverse voltage	$T_j = 25^\circ\text{C}$	V_{RRM}	1200	V
连续正向直流电流 Continuous DC forward current		I_F	75	A
正向重复峰值电流 Repetitive peak forward current	$t_p = 1\text{ ms}$	I_{FRM}	150	A

特征值 / Characteristic Values

			Min.	Typ.	Max.	
正向电压/Forward voltage	$I_F = 75\text{ A}, V_{GE} = 0\text{ V}$	$T_j = 25^\circ\text{C}$ $T_j = 125^\circ\text{C}$	V_F	2.4 2.2		V
反向恢复峰值电流 Peak reverse recovery current	$I_F = 75\text{ A}, V_R = 600\text{ V}$ $V_{GE} = -15\text{ V}$ $-di_F/dt = 1200\text{ A}/\mu\text{s}$	$T_j = 25^\circ\text{C}$ $T_j = 125^\circ\text{C}$	I_{RM}	36 57		A
恢复电荷/Recovered charge		$T_j = 25^\circ\text{C}$ $T_j = 125^\circ\text{C}$	Q_r	3.6 13.2		μC
反向恢复损耗 Reverse recovery energy		$T_j = 25^\circ\text{C}$ $T_j = 125^\circ\text{C}$	E_{rec}	2.26 5.34		mJ
结 - 外壳热阻 Thermal resistance, junction to case	每个二极管 / per diode		R_{thJC}		0.50	K/W
在开关状态下温度 Temperature under switching			T_{jop}	-40	125	$^\circ\text{C}$

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反向二极管 / Diode, Reverse



最大额定值 / Maximum Rated Values

反向重复峰值电压 Repetitive peak reverse voltage	$T_j = 25^\circ\text{C}$	V_{RRM}	1200	V
连续正向直流电流 Continuous DC forward current		I_F	75	A
正向重复峰值电流 Repetitive peak forward current	$t_p = 1\text{ ms}$	I_{FRM}	150	A

特征值 / Characteristic Values

			Min.	Typ.	Max.	
正向电压/Forward voltage	$I_F = 75\text{ A}, V_{GE} = 0\text{ V}$	$T_j = 25^\circ\text{C}$ $T_j = 125^\circ\text{C}$	V_F	2.4 2.2		V
反向恢复峰值电流 Peak reverse recovery current	$I_F = 75\text{ A}, V_R = 600\text{ V}$ $V_{GE} = -15\text{ V}$ $-di_F/dt = 1200\text{ A}/\mu\text{s}$	$T_j = 25^\circ\text{C}$ $T_j = 125^\circ\text{C}$	I_{RM}	36 57		A
恢复电荷/Recovered charge		$T_j = 25^\circ\text{C}$ $T_j = 125^\circ\text{C}$	Q_r	3.6 13.2		μC
反向恢复损耗 Reverse recovery energy		$T_j = 25^\circ\text{C}$ $T_j = 125^\circ\text{C}$	E_{rec}	2.26 5.34		mJ
结 - 外壳热阻 Thermal resistance, junction to case	每个二极管 / per diode		R_{thJC}		0.50	K/W
在开关状态下温度 Temperature under switching			T_{jop}	-40	125	$^\circ\text{C}$

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模块 / Module



绝缘测试电压 Isolation test voltage	RMS, f = 50 Hz, t = 1 min.	V_{ISOL}	2.5	kV
模块基板材料 Material of module baseplate			Cu	
内部绝缘/Internal isolation	基本绝缘 (class 1, IEC 61140) Basic insulation (class1, IEC 61140)		Al_2O_3	
爬电距离/Creepage distance	端子至散热器 / terminal to heatsink 端子至端子 / terminal to terminal		17.0 20.0	mm
电气间隙/Clearance	端子至散热器 / terminal to heatsink 端子至端子 / terminal to terminal		17.0 9.5	mm
相对电痕指数 Comperative tracking index		CTI	> 200	

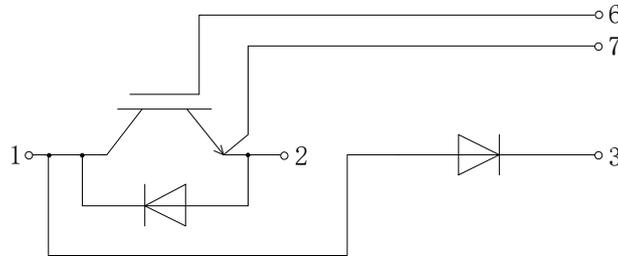
			Min.	Typ.	Max.	
杂散电感, 模块 Stray inductance module		L_{SCE}		30		nH
模块引线电阻 Module lead resistance	$T_c = 25^\circ C$, 每个开关 / per switch	$R_{CC'+EE'}$		0.65		m Ω
储存温度/Storage temperature		T_{stg}	-40		125	$^\circ C$
模块安装的安装扭矩 / Mounting torque for module mounting	螺丝 M6 / Screw M6	M	3.00		5.00	Nm
端子联接扭矩 Terminal connection torque	螺丝 M5 / Screw M5	M	2.5		5.0	Nm
重量/Weight		G		150		g

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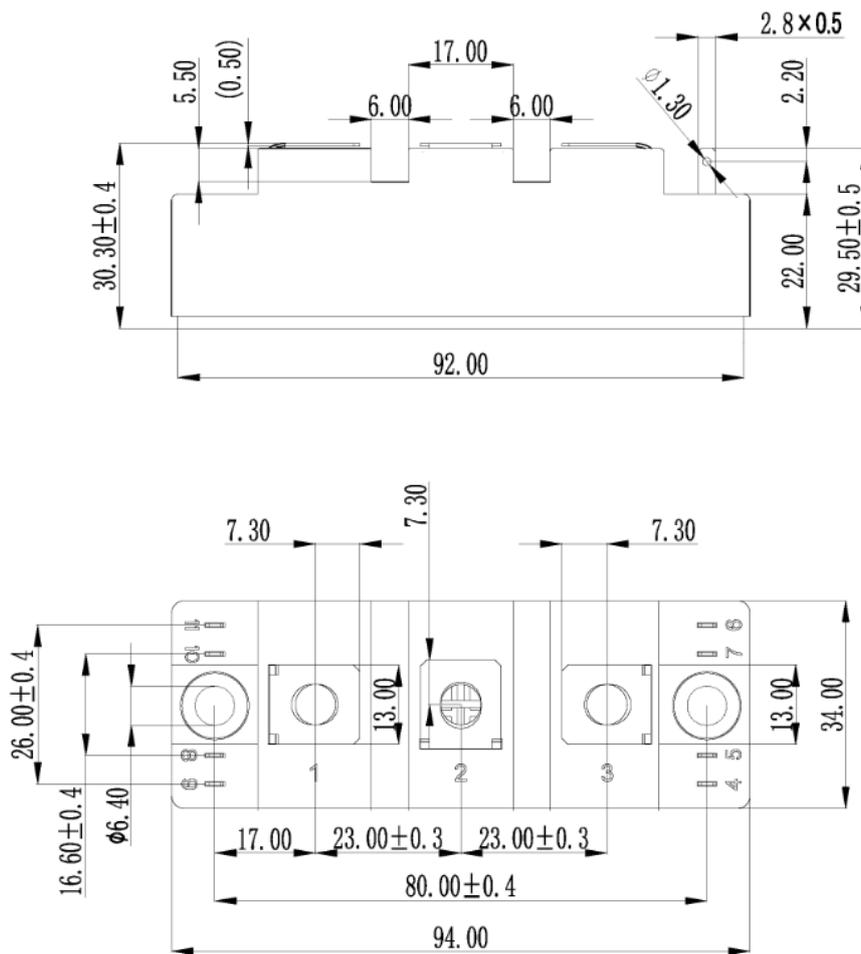
封装 / Package



接线图 / Circuit Diagram



封装尺寸 / Package outlines

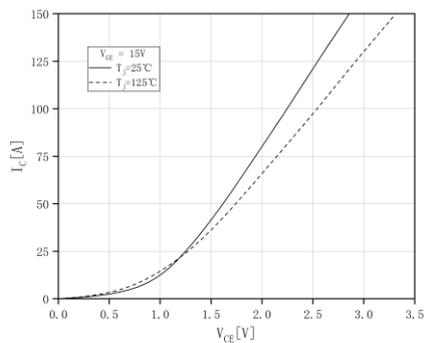


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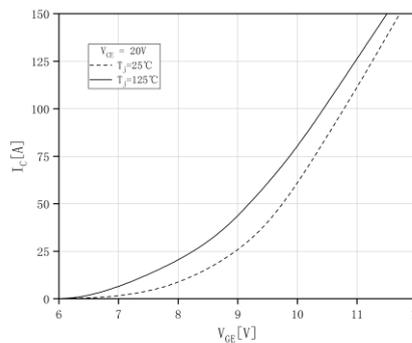
性能 / Performance



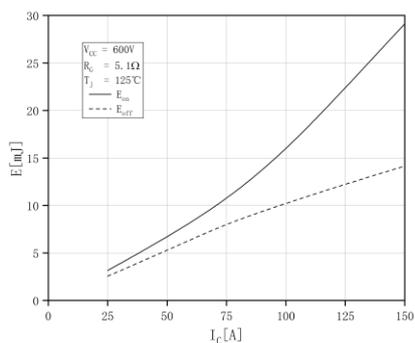
输出特性 IGBT, 制动-斩波器 (典型)
output characteristic IGBT, Chopper (typical)



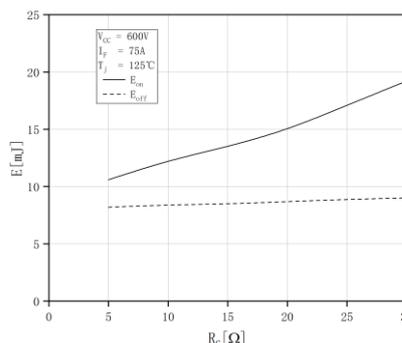
传输特性 IGBT, 制动-斩波器 (典型)
output characteristic IGBT, Chopper (typical)



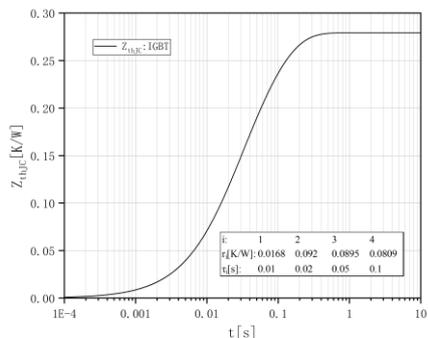
开关损耗 IGBT, 制动-斩波器 (典型)
switching losses IGBT, Chopper (typical)



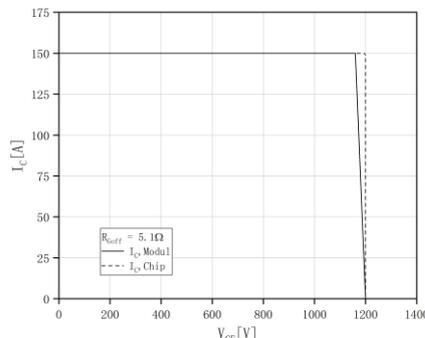
开关损耗 IGBT, 制动-斩波器 (典型)
switching losses IGBT, Chopper (typical)



瞬态热阻抗 IGBT, 制动-斩波器
transient thermal impedance IGBT, Chopper



反偏安全工作区 IGBT, 制动-斩波器 (RBSOA)
Reverse bias safe operating area IGBT, Chopper (RBSOA)

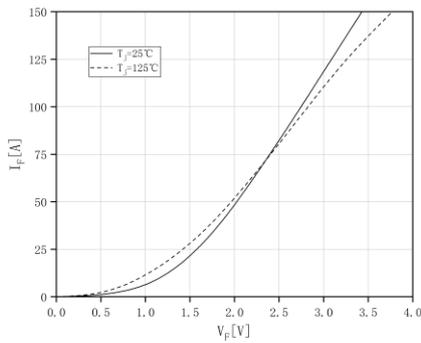


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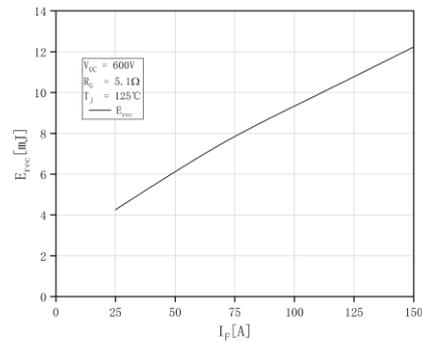
性能 / Performance



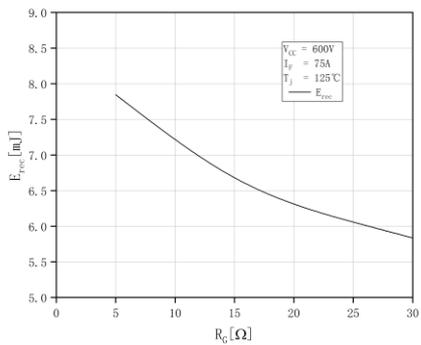
正向偏压特性 二极管, 制动-斩波器 (典型)
forward characteristic of Diode, Chopper (typical)



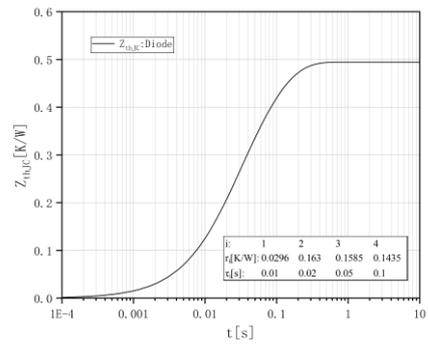
开关损耗 二极管, 制动-斩波器 (典型)
switching losses Diode, Chopper (typical)



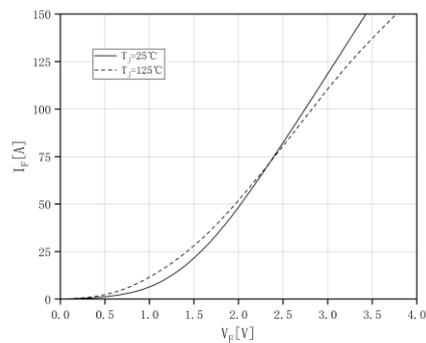
开关损耗 二极管, 制动-斩波器 (典型)
switching losses Diode, Chopper (typical)



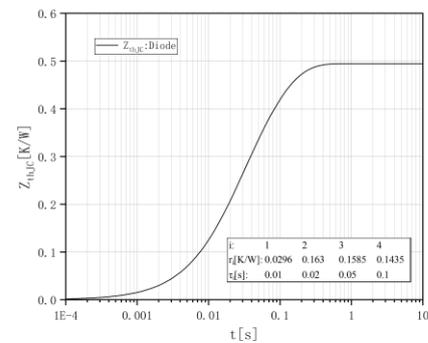
瞬态热阻抗 二极管, 制动-斩波器
transient thermal impedance Diode, Chopper



正向偏压特性 反向二极管 (典型)
forward characteristic of Diode, Reverse (typical)



瞬态热阻抗 反向二极管
transient thermal impedance Diode, Reverse



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